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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/981,402	10/17/2001	Yoshihiro Satoh	N32040200W 6789	
7590 10/26/2004			EXAMINER	
Darryl G. Walker			RICHARDS, N DREW	
WALKER & SA	AKO, LLP			
Suite 235			ART UNIT	PAPER NUMBER
300 South First Street			2815	
San Jose, CA 95113			DATE MAILED: 10/26/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	
	09/981,402	SATOH, YOSHIHIRO	
Office Action Summary	Examiner	Art Unit	
	N. Drew Richards	2815	
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with the c	orrespondence address	
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a repl If NO period for reply is specified above, the maximum statutory period or  - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be tin y within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from b, cause the application to become ABANDONE	nely filed  s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).	
Status			
<ol> <li>Responsive to communication(s) filed on <u>27 S</u></li> <li>This action is <b>FINAL</b>. 2b) This</li> <li>Since this application is in condition for alloward closed in accordance with the practice under E</li> </ol>	s action is non-final. nce except for formal matters, pro		
Disposition of Claims			
4) ☐ Claim(s) 1,2,7-20 and 25 is/are pending in the 4a) Of the above claim(s) 7-20 is/are withdrawn 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1,2 and 25 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or and/or claim(s) are subject to restriction are claim(s) are subject to restriction are claim(s) are subject to restriction and/or claim(s) are subject to restriction are claim(s)	n from consideration.		
Application Papers			
9) ☐ The specification is objected to by the Examine 10) ☑ The drawing(s) filed on 28 July 2003 is/are: a)  Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Example 11.	☑ accepted or b)☐ objected to l drawing(s) be held in abeyance. Set tion is required if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).	
Priority under 35 U.S.C. § 119			
a) ☐ Acknowledgment is made of a claim for foreign a) ☐ All b) ☐ Some * c) ☐ None of:  1. ☐ Certified copies of the priority document 2. ☐ Certified copies of the priority document 3. ☐ Copies of the certified copies of the priority application from the International Burear * See the attached detailed Office action for a list	s have been received. Is have been received in Applicati Inity documents have been receive In (PCT Rule 17.2(a)).	ion No ed in this National Stage	
Attachment(s)			
1) X Notice of References Cited (PTO-892)	4) Interview Summary		
<ol> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date</li> </ol>	Paper No(s)/Mail Da 5) Notice of Informal F 6) Other:	ate Patent Application (PTO-152)	

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#### **DETAILED ACTION**

## Response to Amendment

1. Upon updating the examiner's search, new references have been found such that claims 1, 2 and 25 are no longer allowable. Therefore, the finality of the rejection of the last Office Action is withdrawn and prosecution is reopened. Applicant's most recently filed amendment has been entered since prosecution is reopened. On 10/14/04 the examiner received authorization from Darryl Walker to cancel non-elected claims 7-20. Since this application is no longer considered in condition for allowance the previously authorized examiner's amendment is not being made at this time and claims 7-20 are still withdrawn from consideration.

## Allowable Subject Matter

2. The indicated allowability of claims 1, 2 and 25 is withdrawn in view of the newly discovered reference(s) to Yoshihara et al. (US Pub. 2003/0132525 A1). Rejections based on the newly cited reference(s) follow.

## Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States

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only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

4. Claims 1, 2 and 25 are rejected under 35 U.S.C. 102(e) as being anticipated by Yoshihara et al. (US Pub. 2003/0132525 A1).

Yoshihara et al. disclose a semiconductor device comprising:

a contact 131 which penetrates an interlayer insulating film 103 and is electrically connected with a diffusion layer 113 in the silicon substrate 101 (figure 4);

a gate electrode 111 which if formed on the silicon substrate and contains a nitride film at upper and side portions (figures 12-14 show the formation of the gate electrode including nitride 8 at an upper portion and nitride 10 at a sidewall portion, see paragraphs 100-103);

an insulating film formed from a gas containing carbon (the capacitor dielectric is disclosed in paragraph 120 as being tantalum oxide; the film being formed from a gas containing carbon is a product-by-process limitation that does not structurally distinguish over the prior art); and

a silicon nitride film 121 for preventing carbon diffusion (the silicon nitride film will inherently prevent carbon diffusion to some degree), having a portion sandwiched between the interlayer insulator 103 and the silicon substrate 101 and adjacent to the gate electrode 111 in a direction essentially parallel to a substrate surface, such a sandwiched portion having a thickness in a direction perpendicular to the substrate surface that is less than a thickness of the gate electrode in the perpendicular direction, the silicon nitride film traversing a region except a portion for providing the electrical

connection between the contact and the diffusion layer, and is formed on the nitride film at the upper and side portions of the gate electrode (figure 4).

With regard to claim 2, the insulating film is disclosed as tantalum oxide. This broad disclosure of the genus of tantalum oxide anticipates the specific species of  $Ta_2O_5$ . Further, the claim reads "tantalum oxide  $(Ta_2O_5)$ " so that one would reasonably conclude that tantalum oxide is the same as  $Ta_2O_5$ . The device is also disclosed as being a dynamic random access memory having a memory cell capacitor including the tantalum oxide.

With regard to claim 25, the silicon nitride film for preventing carbon diffusion includes a portion having a bottom surface in contact with and extending parallel to the diffusion layer away from the gate electrode and a top surface in contact with the interlayer insulating film (see figure 4).

#### Conclusion

- 5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Liaw (U.S. Patent No. 5,807,779), Ohuchi et al. (U.S. Patent No. 6,642,585 B2).
- 6. Applicant's amendment submitted 3/9/04 necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a). A shortened statutory period for reply to this final action is set

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to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to N. Drew Richards whose telephone number is (571) 272-1736. The examiner can normally be reached on Monday-Friday 9:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

MPCTZ III

GEÖRGE ECKERT PRIMARY EXAMINER